

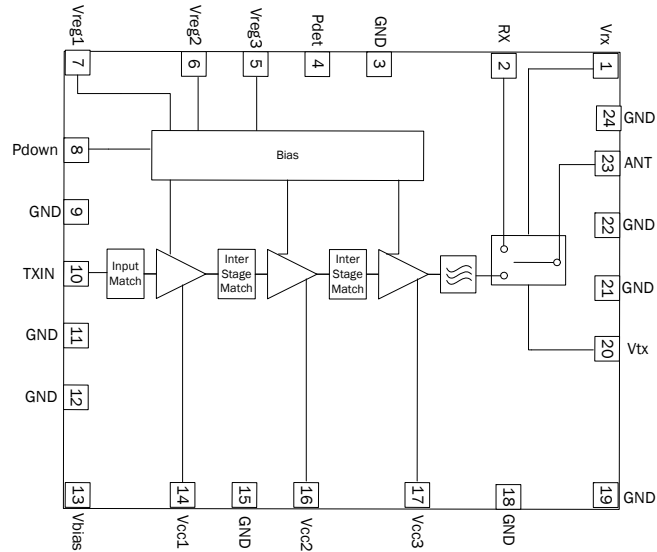


### Features

- 34dB Typical Gain Across Frequency Band
- $P_{OUT} = 25\text{dBm} < 2.5\%$  Dynamic EVM
- 2.4GHz to 2.5GHz Frequency Range
- Integrated Three-Stage PA, Filtering and T/R switch
- High Impedance Control Integrated Power Detector

### Applications

- WiFi IEEE802.11b/g/n Applications
- Customer Premises Equipment (CPE)
- Spread-Spectrum and MMDS Systems



Functional Block Diagram

### Product Description

RFFM4201 is a 1 x 1 MIMO module that is intently specified to address IEEE 802.11b/g/n WiFi 2.4GHz to 2.5GHz customer premises equipment (CPE) applications. The module has an integrated three-stage linear power amplifier, Tx harmonic filtering and SPDT switch. The RFFM4201 has fully matched input and output for a 50Ω system and incorporates matching networks optimized for linear output power and efficiency. The RFFM4201 is housed in a 6mm x 6mm laminate.

### Ordering Information

|                 |                                     |
|-----------------|-------------------------------------|
| RFFM4201PCK-410 | RFFM4201 Eval Board and 5-Piece Bag |
| RFFM4201SB      | 5-Piece Bag                         |
| RFFM4201SR      | 100-Piece Reel                      |
| RFFM4201TR7     | 2500-Piece Reel                     |
| RFFM4201SQ      | 25-Piece Bag                        |

### Optimum Technology Matching® Applied

- |   |                                      |  |                                    |
|---|--------------------------------------|--|------------------------------------|
| <input type="checkbox"/> GaAs HBT             | <input type="checkbox"/> SiGe BiCMOS | <input checked="" type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT  |
| <input type="checkbox"/> GaAs MESFET          | <input type="checkbox"/> Si BiCMOS   | <input type="checkbox"/> Si CMOS               | <input type="checkbox"/> BiFET HBT |
| <input checked="" type="checkbox"/> InGaP HBT | <input type="checkbox"/> SiGe HBT    | <input type="checkbox"/> Si BJT                | <input type="checkbox"/> LD MOS    |

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## Absolute Maximum Ratings

| Parameter                      | Rating        | Unit |
|--------------------------------|---------------|------|
| Supply Voltage (RF Applied)    | -0.5 to +5.25 | V    |
| Supply Voltage (No RF Applied) | -0.5 to +6.0  | V    |
| DC Supply Current              | 750           | mA   |
| Input RF Power                 | +10*          | dBm  |
| Operating Temperature          | -30 to +85    | °C   |
| Storage Temperature            | -40 to +150   | °C   |
| Moisture Sensitivity           | MSL3          |      |

\*Maximum Input Power with a 50Ω load.



**Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

| Parameter   | Specification |      |        | Unit    | Condition   |
|---|---------------|------|--------|---------|---|
|   | Min.          | Typ. | Max.   |         |   |
| Typical Conditions                                  |               |      |        |         | T = 25 °C, V <sub>CC</sub> = 5.0V, V <sub>REG</sub> = 2.9V, using an IEEE802.11g waveform, 54Mbps, unless otherwise noted |
| Frequency   | 2412          |      | 2484   | MHz     |   |
| Tx Performance - 11g/n                              |               |      |        |         | Compliance with standard 802.11g/n  |
| 802.11n Output Power                                | 25            | 25.5 |        | dBm     | 802.11n HT20 and HT40 MCS7  |
| 11n Dynamic EVM                                     |               | 2.5  | 3      | %       |   |
| 802.11n Output Power                                |               | 25.8 |        | dBm     | At V <sub>CC</sub> = 5.25V; 802.11n HT20 and HT40 MCS7  |
| 11n Dynamic EVM                                     |               | 2.5  | 3      | %       |   |
| 802.11g Output Power                                | 25.5          | 26   |        | dBm     | 802.11g 64QAM 54Mbps  |
| 11g Dynamic EVM                                     |               | 2.5  | 3      | %       |   |
| Second Harmonic                                     |               | -47  | -42    | dBm/MHz | 11n HT40 MCS0/7. At rated P <sub>OUT</sub>  |
| Third Harmonic                                      |               | -50  | -42    | dBm/MHz | 11n HT40 MCS0/7. At rated P <sub>OUT</sub>  |
| Tx Performance - Spectral Mask                      |               |      |        |         | Compliance with standard 802.11b/n  |
| 802.11b Output Power                                |               | 25.5 |        | dBm     | Meet 802.11b CCK 1Mbps Mask Spec  |
| 802.11n Output Power                                |               | 25   |        | dBm     | Meet 802.11n HT20/HT40 MCS7 Mask  |
| Tx Performance - Generic                            |               |      |        |         |   |
| Gain  | 31.5          | 34   | 37     | dB      | At rated P <sub>OUT</sub>   |
| Gain Variation over Temp                            |               |      | +/-2.5 | dB      | Over temperature of -40 °C to +85 °C  |
| Low Gain Mode - Gain Reduction                      |               | 23   |        | dB      | Drop in gain versus high gain mode by setting V <sub>REG2</sub> = 0   |
| Power Detect Range                                  | 0.125         |      | 2.3    | V       | P <sub>OUT</sub> = 5dBm to 30dBm  |
| Power Detect Voltage                                |               | 1.45 |        | V       | At rated P <sub>OUT</sub>   |
| Input Return Loss - TX_IN pin                       | 10            | 15   |        | dB      | In specified frequency band   |
| Output Return Loss at ANT pin                       | 6             | 8    |        | dB      | In specified frequency band   |
| Operating Current                                   |               | 435  | 500    | mA      | At rated P <sub>OUT</sub>   |
| Quiescent Current                                   |               | 160  | 210    | mA      | V <sub>CC</sub> = 5.0, V <sub>REG</sub> = 2.9V and RF = OFF   |
| PAE (Power Added Efficiency)                        |               | 20   |        | %       | At rated P <sub>OUT</sub> (PA only)   |
| I <sub>REG</sub>                                    |               | 4    | 8.5    | mA      | in Tx mode  |
| P <sub>DOWN</sub> Current - V <sub>REG</sub> supply |               | 7    | 10     | mA      | P <sub>DOWN</sub> = 0V, V <sub>REG</sub> = 2.9V, V <sub>CC</sub> = 5V   |
| P <sub>DOWN</sub> Current - V <sub>CC</sub> Supply  |               | 0.5  | 1      | mA      | P <sub>DOWN</sub> = 0V, V <sub>REG</sub> = 2.9V, V <sub>CC</sub> = 5V   |
| Leakage Current                                     |               | 0.2  | 0.6    | mA      | V <sub>CC</sub> = 5V, V <sub>REG</sub> = 0V, P <sub>DOWN</sub> = 0V   |
| Power Supply - V <sub>CC</sub>                      |               | 5    | 5.25   | V       |   |

| Parameter  | Specification |      |      | Unit           | Condition                                 |
|--|---------------|------|------|----------------|---|
|  | Min.          | Typ. | Max. |                |   |
| Typical Conditions (continued)                                     |               |      |      |                |   |
| Power Supply - $V_{REG1}$ , $V_{REG2}$ , $V_{REG3}$                | 2.8           | 2.9  | 3    | V              |   |
| Turn-on time from setting of $V_{REG1}$ , $V_{REG2}$ , $V_{REG3}$  |               |      | 400  | ns             | Output stable to within 90% of final gain |
| Turn-off time from setting of $V_{REG1}$ , $V_{REG2}$ , $V_{REG3}$ |               |      | 800  | ns             | Output stable to within 90% of final gain |
| Stability  | -25           |      | 30   | dBm            | No spurs above -47dBm into 4:1 VSWR       |
| CW P1dB  |               | 32   |      | dBm            | Tx mode in 50% Duty Cycle                 |
| Rx Performance   |               |      |      |                |   |
| Rx Insertion Loss - RX   |               | 0.8  | 1    | dB             |   |
| Noise Figure   |               | 0.8  | 1    | dB             | In specified frequency band               |
| Return Loss - RX   | 10            | 16   |      | dB             |   |
| RX to Ant Isolation while in Tx Mode                               |               | 30   |      | dB             |   |
| RX to TX Isolation while in Tx Mode                                | 25            | 30   |      | dB             |   |
| Generic Performance  |               |      |      |                |   |
| T/R Switching Time   |               |      | 0.5  | $\mu$ s        |   |
| Voltage Logic High   | 2.75          | 2.9  | 3.4  | V              |   |
| Voltage Logic Low  | 0             |      | 0.3  | V              |   |
| Control Current - Logic High                                       |               | 1    | 10   | $\mu$ A        |   |
| Thermal  |               |      |      |                |   |
| $R_{THJ}$  |               | 30   |      | $^{\circ}$ C/W |   |
| ESD  |               |      |      |                |   |
| Human Body Model   | 250           |      |      | V              | EIA/JESD22-114A RF pins                   |
|  | 500           |      |      | V              | EIA/JESD22-114A DC pins                   |
| Charge Device Model  | 500           |      |      | V              | JESD22-C101C all pins                     |

| Truth Table |       |     |     |
|-------------|-------|-----|-----|
| Status      | PDOWN | VTX | VRX |
| Tx Mode     | 1     | 1   | 0   |
| Rx Mode     | 0     | 0   | 1   |

## Pin Names and Descriptions

| Pin      | Name  | Description  |
|----------|-------|--|
| 1        | VRX   | Switch control for Rx mode   |
| 2        | RX    | RF output is internally matched to 50Ω and DC blocked.   |
| 3        | GND   | Ground connection  |
| 4        | PDET  | Power detector provides an output voltage proportional to the RF output power level.   |
| 5        | VREG3 | Third stage bias voltage. This pin requires regulated supply for best performance.   |
| 6        | VREG2 | Second stage bias voltage. This pin requires regulated supply for best performance.  |
| 7        | VREG1 | First stage bias voltage. This pin requires regulated supply for best performance.   |
| 8        | PDOWN | Power down pin. Apply <math><0.3V_{DC}</math> to power down the three power amplifier stages. Apply <math>1.75V_{DC}</math> to <math>5.0V_{DC}</math> to power up. If function is not desired, pin may be connected to VREG. |
| 9        | GND   | Ground connection  |
| 10       | TXIN  | RF input is internally matched to 50Ω and DC blocked.  |
| 11       | GND   | Ground connection  |
| 12       | GND   | Ground connection  |
| 13       | VBIAS | Supply voltage for the bias reference and control circuits.  |
| 14       | VCC1  | This pin is connected internally to the collector of the 1st stage RF device. To achieve specified performance, the layout of these pins should match the recommended land pattern.  |
| 15       | GND   | Ground connection  |
| 16       | VCC2  | This pin is connected internally to the collector of the 2nd stage RF device. To achieve specified performance, the layout of these pins should match the recommended land pattern.  |
| 17       | VCC3  | This pin is connected internally to the collector of the 3rd stage RF device. To achieve specified performance, the layout of these pins should match the recommended land pattern.  |
| 18       | GND   | Ground connection  |
| 19       | GND   | Ground connection  |
| 20       | VTX   | Switch control for Tx mode   |
| 21       | GND   | Ground connection  |
| 22       | GND   | Ground connection  |
| 23       | ANT   | RF Output is internally matched to 50Ω and DC blocked.   |
| 24       | GND   | Ground connection  |
| PKG Base | GND   | Ground connection  |

## Theory of Operation and Applications

The RFFM4201 is a single-chip integrated front end module (FEM) for high performance WiFi applications in the 2.4GHz to 2.5GHz ISM band. The FEM greatly reduces the number of external components minimizing footprint and assembly cost of the overall 802.11b/g/n solution. The RFFM4201 has an integrated b/g/n power amplifier, a power Detector, and Tx filtering and a switch, which is capable of switching between WiFi Rx, WiFi Tx operations. The device is manufactured using InGaP HBT and pHEMT processes on a 6mm x 6mm x 0.95mm laminate package. The module meets or exceeds the RF front end needs of the 802.11b/g/n WiFi RF systems. The RFFM4201 is a very easy part to implement. To reduce the design and optimization process on the customer application, the evaluation board layout should be copied as close as possible, in particular the ground and via configurations. Gerber files of RFMD PCBA designs will be provided upon request. The supply voltage lines should present an RF short to the FEM by using bypass capacitors on the  $V_{CC}$  traces. To simplify bias conditions, the RFFM4201 requires a single positive supply voltage ( $V_{CC}$ ), a positive current control bias ( $V_{REG}$ ) supply, and a positive supply for switch control. The built-in power detector of the RFFM4201 can be used as power monitor in the system. All inputs and outputs are internally matched to 50Ω.

### Transmit Path

The RFFM4201 has a typical gain of 34dB from 2.4GHz to 2.5GHz, and delivers 25.5dBm typical output power in 11n HT20 MCS7 and 26dBm typical in 11g 54Mbps. The RFFM4201 requires a single positive of 5.0V to operate at full specifications. The VREG pin requires a regulated supply at 2.9V to maintain nominal bias current.

### Out of Band Rejection

The RFFM4201 contains a low pass filtering (LPF) to attenuate the 2nd Harmonics to -47dBm/MHz (typical), to meet the out of band rejection requirements of the system for FCC specification.

### Receive Path

The Rx path has a 50Ω single-ended port. The receive port return loss is 9.6dB minimum. In this mode, the FEM has an Insertion loss of 0.8dB and 30dB (typical) isolation to Tx port.

### RFFM4201 Biasing Instructions to the Evaluation Board:

- 802.11b/g/n transmit:
- Connect the FEM to a signal generator at the input and a spectrum analyzer at the output. Set the pin at signal generator is at -20dBm.
- Bias  $V_{CC}$  to 5.0V first with  $V_{REG} = 0.0V$ . If available, enable the current limiting function of the power supply to 750mA.
- Refer to switch operational truth table to set the control lines at the proper levels for WiFi Tx.
- Turn on  $V_{REG}$  to 2.9V (typ.).  
On  $V_{REG}$  (of evaluation board), regulated supply is recommended. Be extremely careful not to exceed 3.0V on the VREG pin or the part may exceed device current limits.
- Turn on  $P_{DOWN}$  to 2.9V (typ.).  $P_{DOWN}$  pin can be tied to  $V_{REG}$  supply.  
**NOTE:** It is important to adjust the  $V_{CC}$  voltage source so that +5V is measured at the board; and the +2.9V of  $V_{REG}$  is measured at the board. The high collector currents will drop the collector voltage significantly if long leads are used. Adjust the bias voltage to compensate.
- Turn on RF of signal generator and gradually increase power level to the rated power.  
**CAUTION:** If the input signal exceeds the rated power, the RFFM4201 Evaluation Board can be permanently damaged.
- To turn off FEM, turn off RF power of signal generator; then  $P_{DOWN}$ ,  $V_{REG}$  and  $V_{CC}$ .
- 802.11b/g/n receive
- To receive WiFi set the switch control lines per the truth table.

## General Layout Guidelines and Considerations:

For best performance the following layout guidelines and considerations must be followed regardless of final use or configuration:

1. The ground pad of the RFFM4201 has special electrical and thermal grounding requirements. This pad is the main RF ground and main thermal conduit path for heat dissipation. The GND pad and vias pattern and size used on the RFMD evaluation board should be replicated. The RFMD layout files in Gerber format can be provided upon request. Ground paths (under device) should be made as short as possible.
2. The RF lines should be well separated with solid ground in between the traces to eliminate any possible RF leakages or cross-talking.
3. Bypass capacitors should be used on the DC supply lines. The VCC lines may be connected after the RF bypass and decoupling capacitors to provide better isolation between each VCC line.

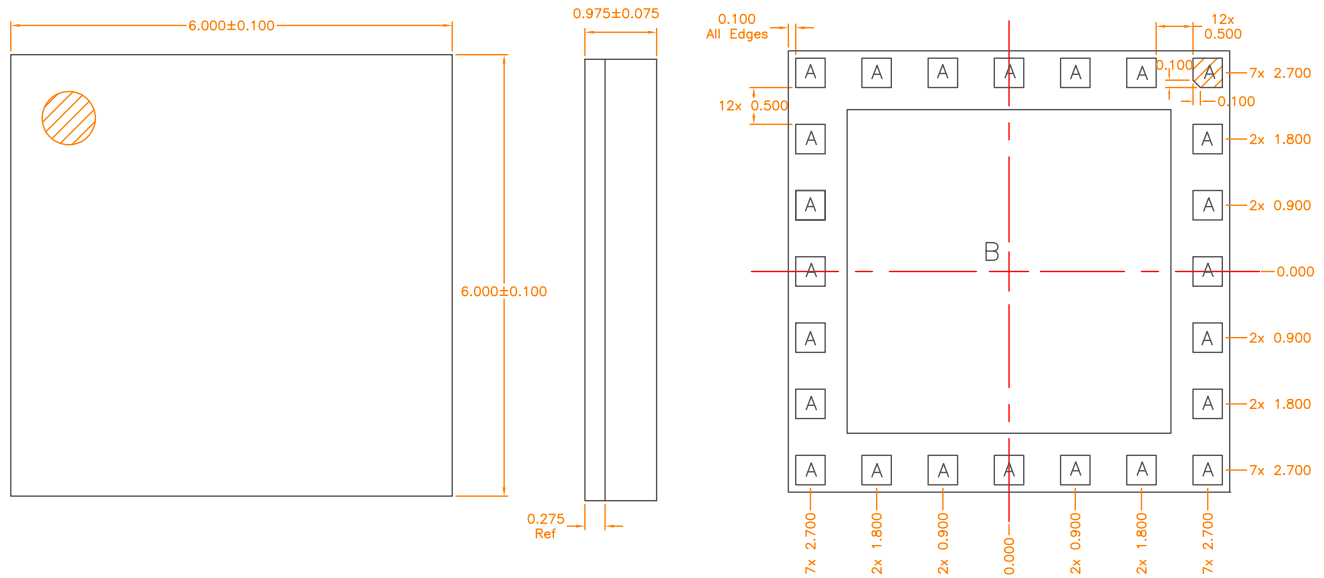
## RFFM4201 Tx Production and System Calibration Recommendation:

It is highly recommended to follow the DC biasing step and RF power settings in the production calibration or test.

1. Connect the RF cables of input and output then connect to the proper equipment.
2. Apply  $V_{CC}$ , then  $V_{REG}$  as per the data sheet recommendations.
3. Set RF input to the desired frequency and initial RF input power at -20dBm. This will insure the power amplifier is in a linear state and not over driven.
4. Set FEM in Tx mode by the truth table.
5. Apply  $P_{DOWN} = \text{high}$
6. Sweep RF from low to high output power and take measurements at the rated output power.
7. Ensure that the output power at turn on does not saturate the power amplifier. The recommended output power should be about 10dB to 20dB below the rated power. Start calibrating from low to high power in reasonable steps until the rated power is reached then take the measurements.

**CAUTION:** If the input signal exceeds the maximum input power specifications, the RFFM4201 could be permanently damaged.

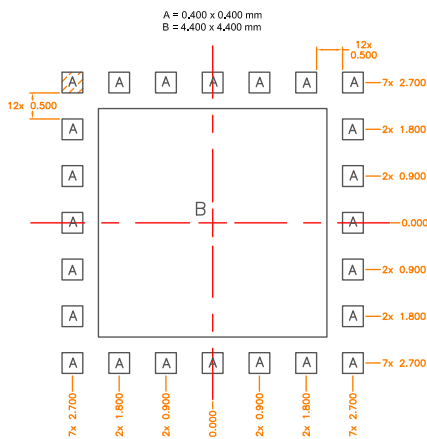
Package Drawing



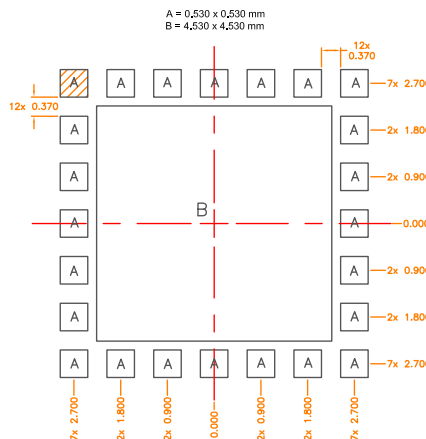
Notes:

1. Shaded area represents Pin 1 location.

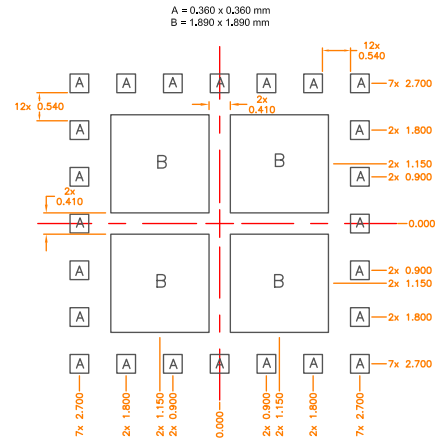
A = 0.400 x 0.400 mm  
B = 4.400 x 4.400 mm



PCB Metal Land Pattern



PCB Solder Mask Pattern



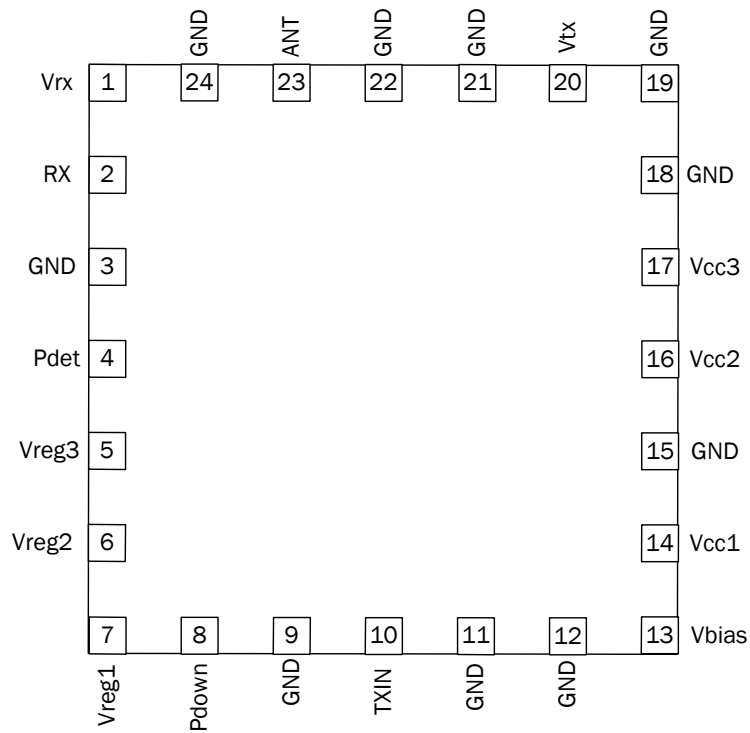
PCB Stencil Pattern

Notes:

1. Shaded area represents Pin 1 location.

**Note:** Thermal vias for center slug “B” should be incorporated into the PCB design. The number and size of thermal vias will depend on the application. Example of the number and size of vias can be found on the RFMD evaluation board layout.

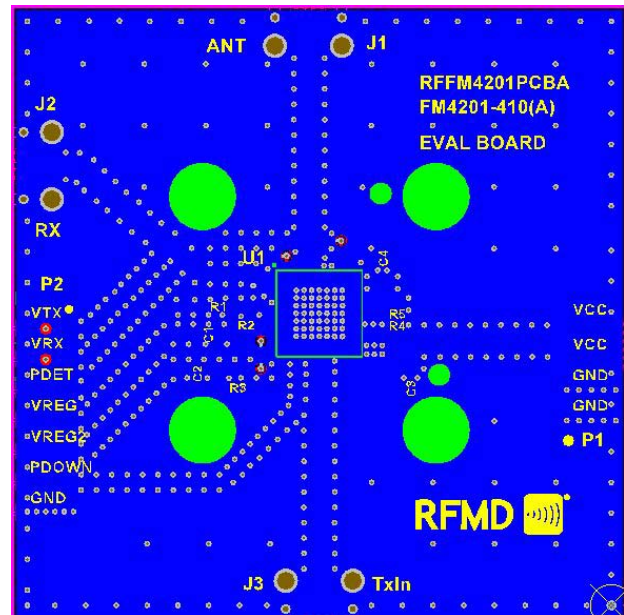
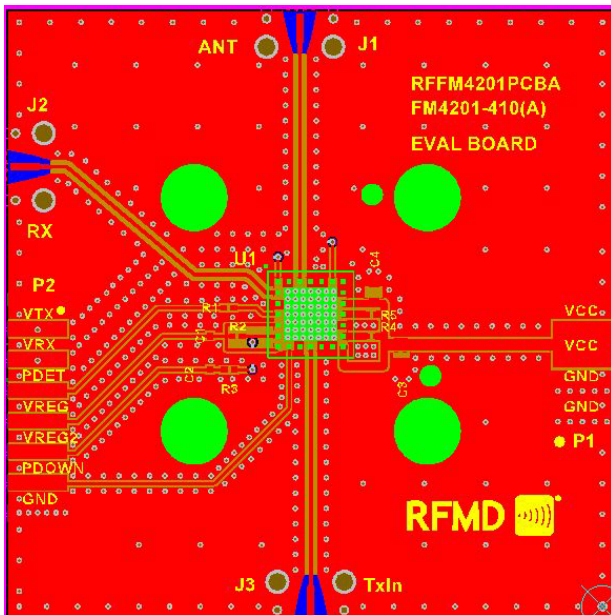
## Pin Out



## Evaluation Board

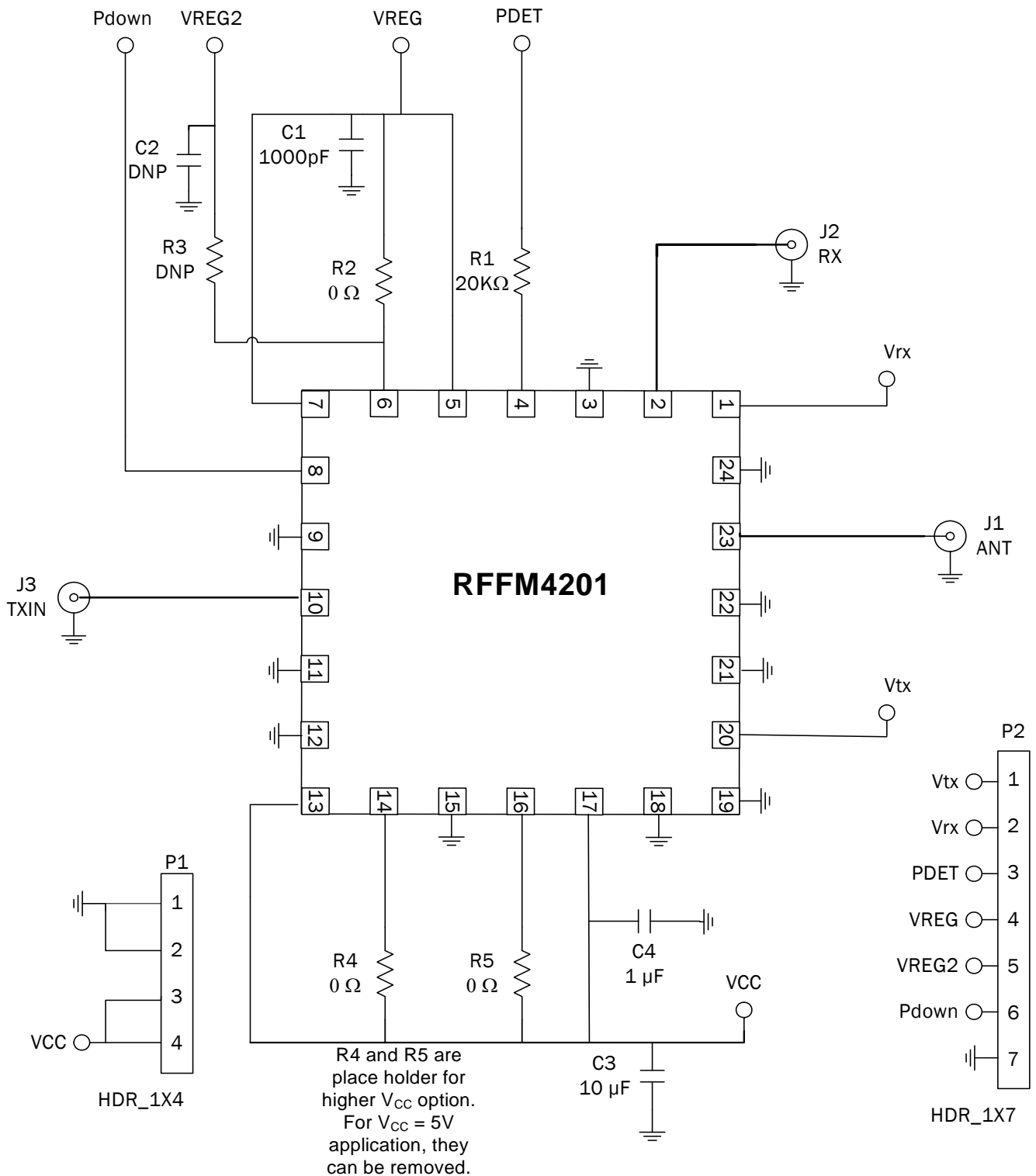
Top Layer

Bottom Layer





**Evaluation Board Schematic**

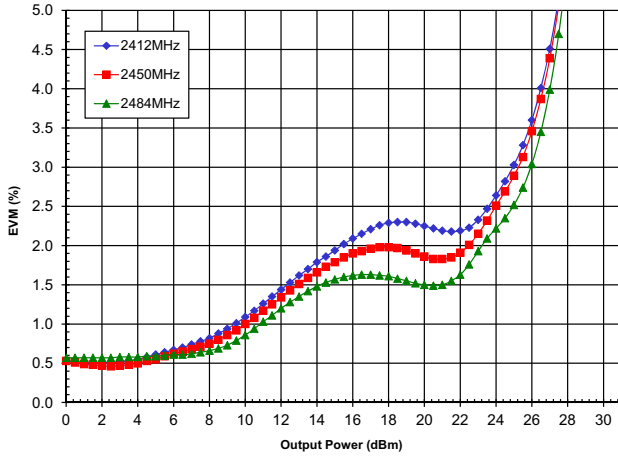


### Bill of Materials

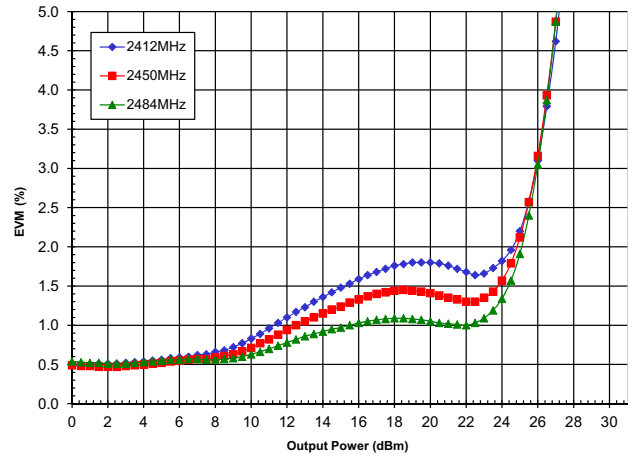
| Description                             | Qty | Reference Designator | Manufacturer            | Manufacturer's P/N |
|---|-----|----------------------|-------------------------|--------------------|
| CAP, 1000pF, 10%, 50V, X7R, 0402        | 1   | C1                   | Murata Electronics      | GRM155R71H102KA01D |
| CAP, 1µF, 10%, 10V, X5R, 0603           | 1   | C4                   | Murata Electronics      | GRM188R61A105KA61D |
| CAP, 10µF, 10%, 10V, X5R, 0805          | 1   | C3                   | Murata Electronics      | RM21BR61A106KE19L  |
| CONN, SMA, END LNCH, UNIV, HYB MNT, FLT | 3   | J1, J2, J3           | MOLEX                   | SD-73251-4000      |
| RES, 20K, 5%, 1/16W, 0402               | 1   | R1                   | PANASONIC INDUSTRIAL CO | ERJ-2GEJ203        |
| RES, 0Ω, 0402                           | 3   | R2, R4, R5           | Kamaya, Inc             | RMC1/16SJPTH       |
| DNI                                     | 2   | R3, C2               |                         |                    |
| RFFM4201                                | 1   | U1                   | RFMD                    | RFFM4201           |

### WiFi 802.11n HT20 MCS7 Performance Plots in 100% Duty Cycle

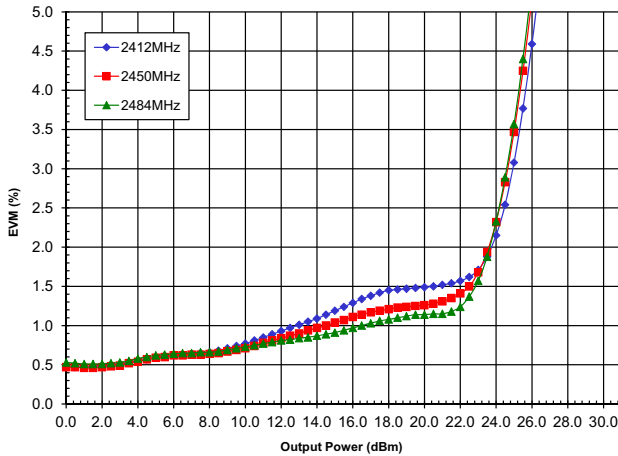
EVM (%) versus  $P_{OUT}$  (dBm)  
-40°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



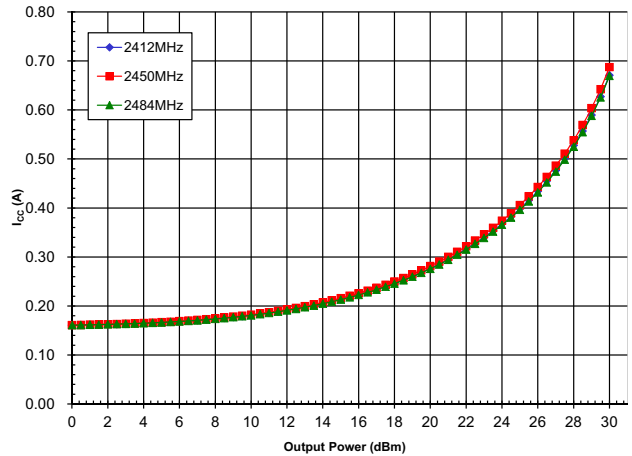
EVM (%) versus  $P_{OUT}$  (dBm)  
25°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



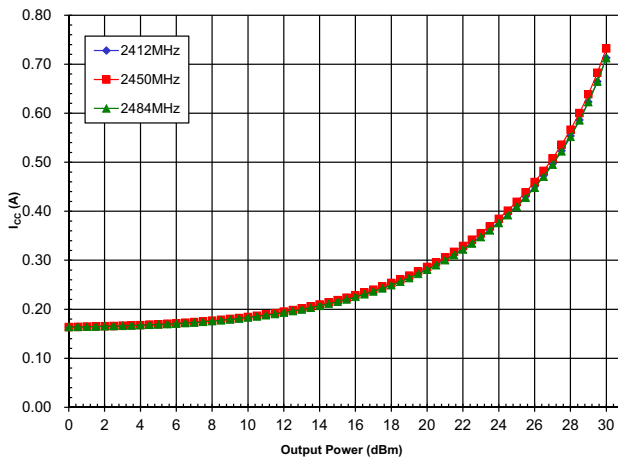
EVM (%) versus  $P_{OUT}$  (dBm)  
85°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



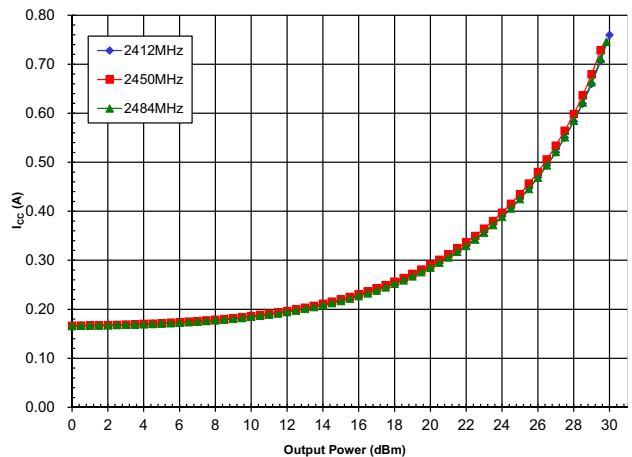
$I_{CC}$  (A) versus  $P_{OUT}$  (dBm)  
-40°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



$I_{CC}$  (A) versus  $P_{OUT}$  (dBm)  
25°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$

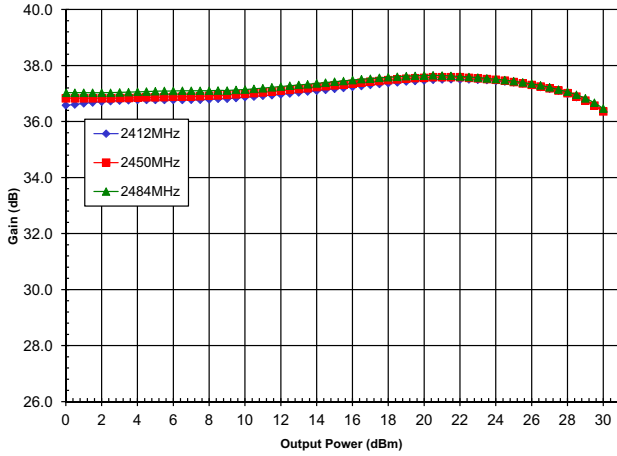


$I_{CC}$  (A) versus  $P_{OUT}$  (dBm)  
85°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$

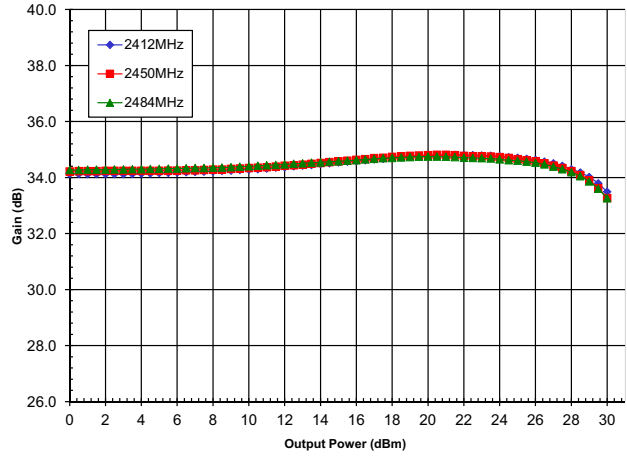


## WiFi 802.11n HT20 MCS7 Performance Plots in 100% Duty Cycle

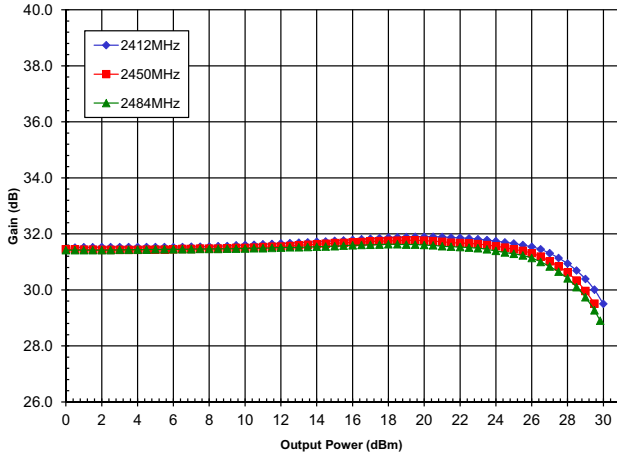
Gain (dB) versus  $P_{OUT}$  (dBm)  
-40°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



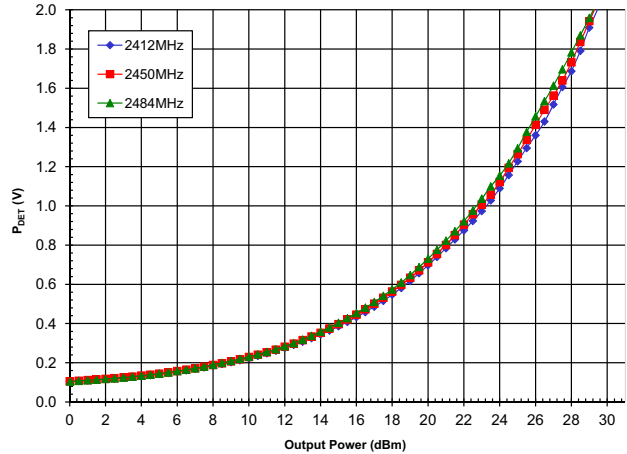
Gain (dB) versus  $P_{OUT}$  (dBm)  
25°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



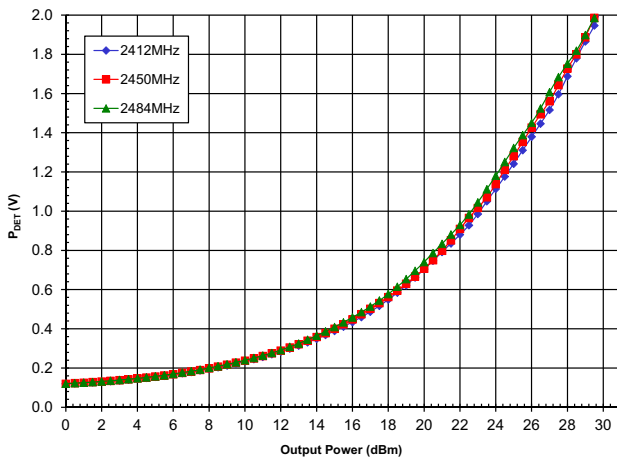
Gain (dB) versus  $P_{OUT}$  (dBm)  
85°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



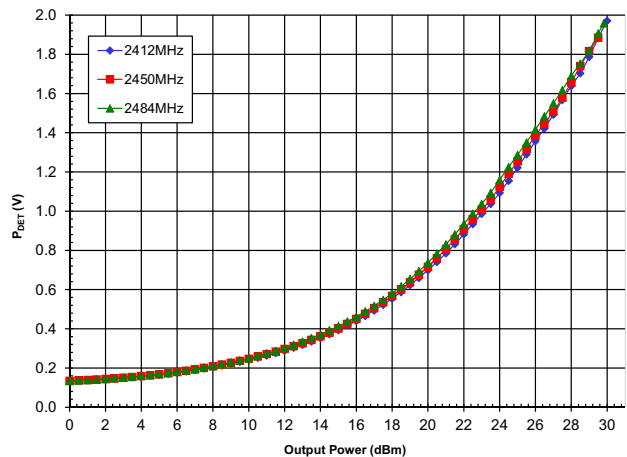
Power Detect (V) versus  $P_{OUT}$  (dBm)  
-40°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



Power Detect (V) versus  $P_{OUT}$  (dBm)  
25°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$

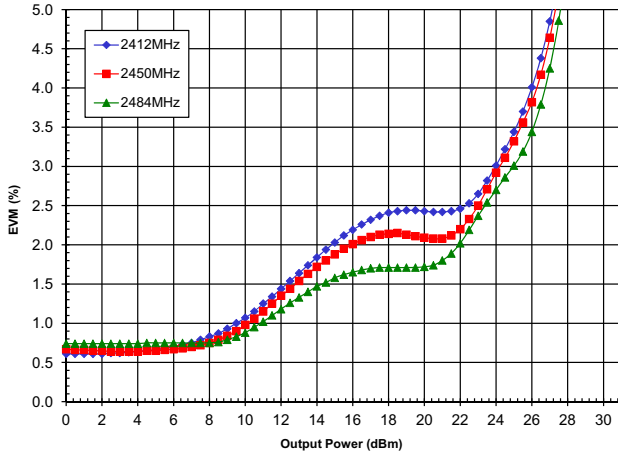


Power Detect (V) versus  $P_{OUT}$  (dBm)  
85°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$

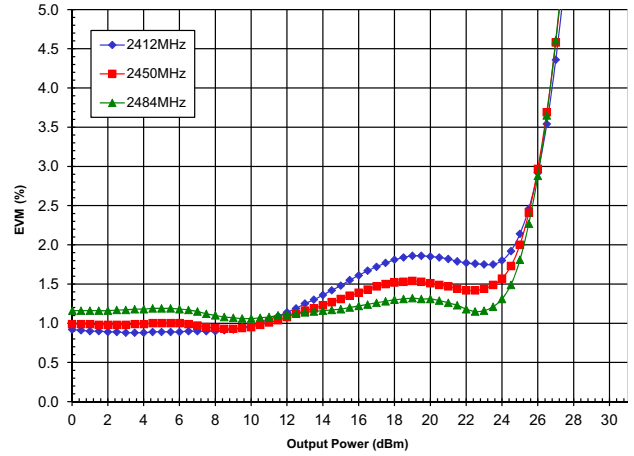


WiFi 802.11n HT20 MCS7 Performance Plots in 50% Duty Cycle

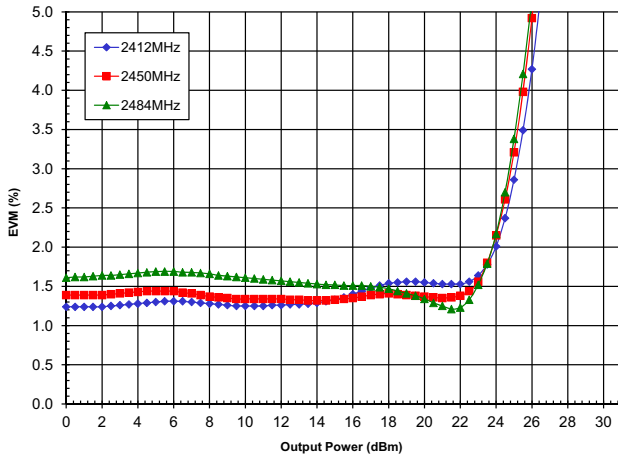
EVM (%) versus P<sub>OUT</sub> (dBm)  
-40°C  
V<sub>CC</sub> = 5V<sub>DC</sub> V<sub>REG</sub> = 2.9V<sub>DC</sub>



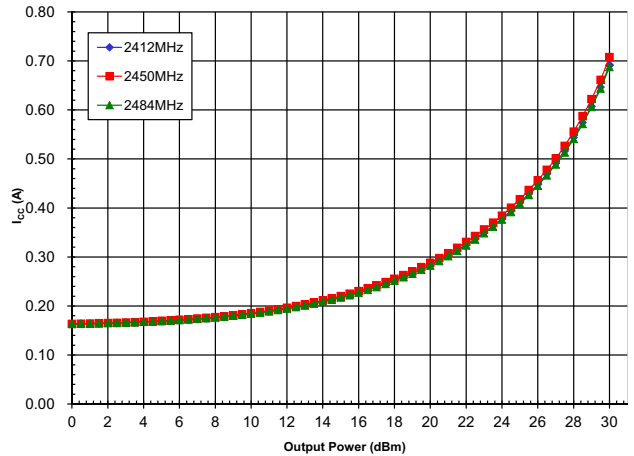
EVM (%) versus P<sub>OUT</sub> (dBm)  
25°C  
V<sub>CC</sub> = 5V<sub>DC</sub> V<sub>REG</sub> = 2.9V<sub>DC</sub>



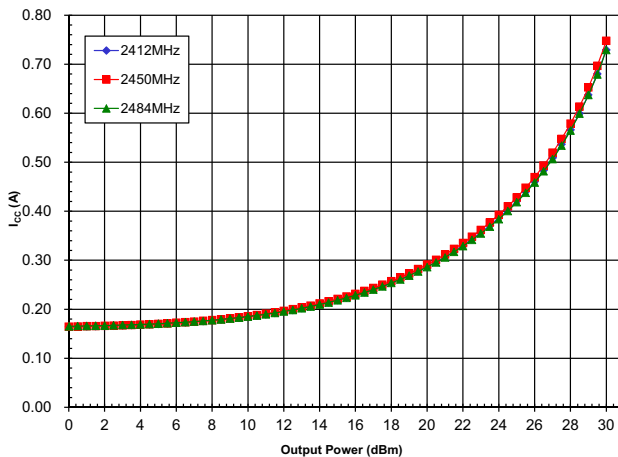
EVM (%) versus P<sub>OUT</sub> (dBm)  
85°C  
V<sub>CC</sub> = 5V<sub>DC</sub> V<sub>REG</sub> = 2.9V<sub>DC</sub>



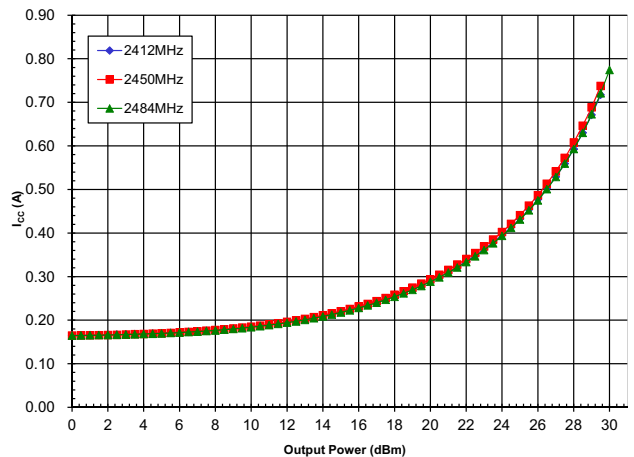
I<sub>CC</sub> (A) versus P<sub>OUT</sub> (dBm)  
-40°C  
V<sub>CC</sub> = 5V<sub>DC</sub> V<sub>REG</sub> = 2.9V<sub>DC</sub>



I<sub>CC</sub> (A) versus P<sub>OUT</sub> (dBm)  
25°C  
V<sub>CC</sub> = 5V<sub>DC</sub> V<sub>REG</sub> = 2.9V<sub>DC</sub>

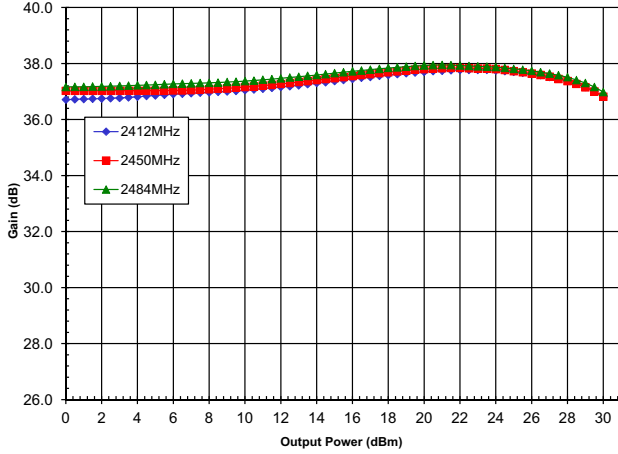


I<sub>CC</sub> (A) versus P<sub>OUT</sub> (dBm)  
85°C  
V<sub>CC</sub> = 5V<sub>DC</sub> V<sub>REG</sub> = 2.9V<sub>DC</sub>

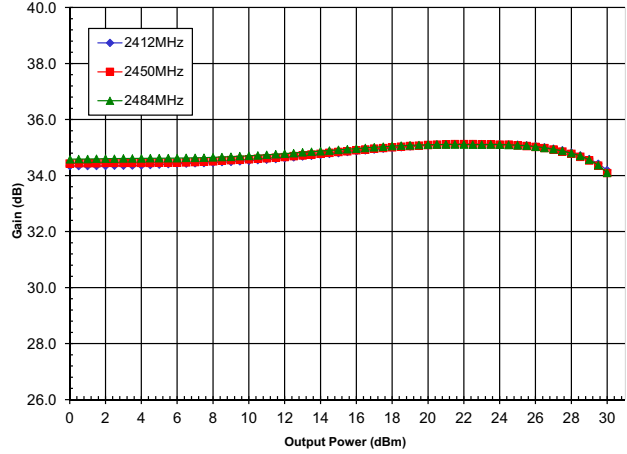


## WiFi 802.11n HT20 MCS7 Performance Plots in 50% Duty Cycle

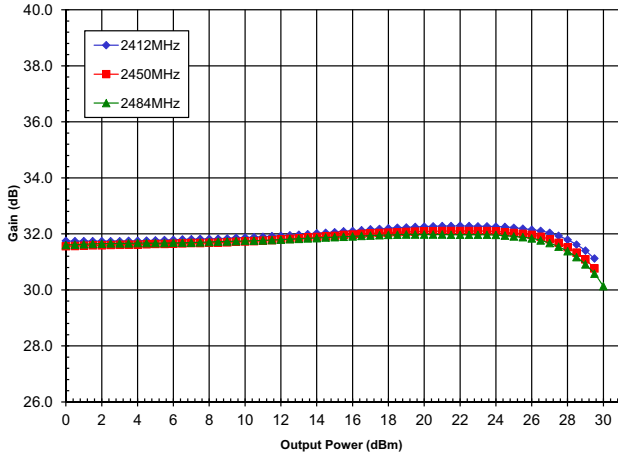
Gain (dB) versus  $P_{OUT}$  (dBm)  
-40°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



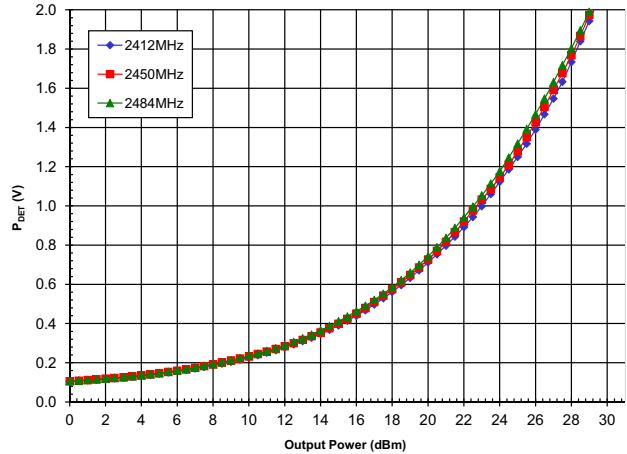
Gain (dB) versus  $P_{OUT}$  (dBm)  
25°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



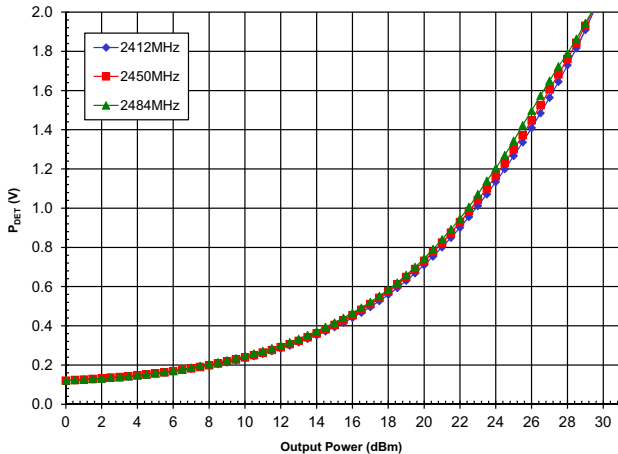
Gain (dB) versus  $P_{OUT}$  (dBm)  
85°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



Power Detect (V) versus  $P_{OUT}$  (dBm)  
-40°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



Power Detect (V) versus  $P_{OUT}$  (dBm)  
25°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$



Power Detect (V) versus  $P_{OUT}$  (dBm)  
85°C  
 $V_{CC} = 5V_{DC}$   $V_{REG} = 2.9V_{DC}$

